

DESCRIPTION

- Collector-Emitter Sustaining Voltage-
: $V_{CEQ(SUS)} = -45V(\text{Min})$
- High DC Current Gain
: $h_{FE} = 750(\text{Min}) @ I_C = -4A$
- Low Collector Saturation Voltage
: $V_{CE(sat)} = -2.5V(\text{Max.}) @ I_C = -4A$
- Complement to Type BDX33

APPLICATIONS

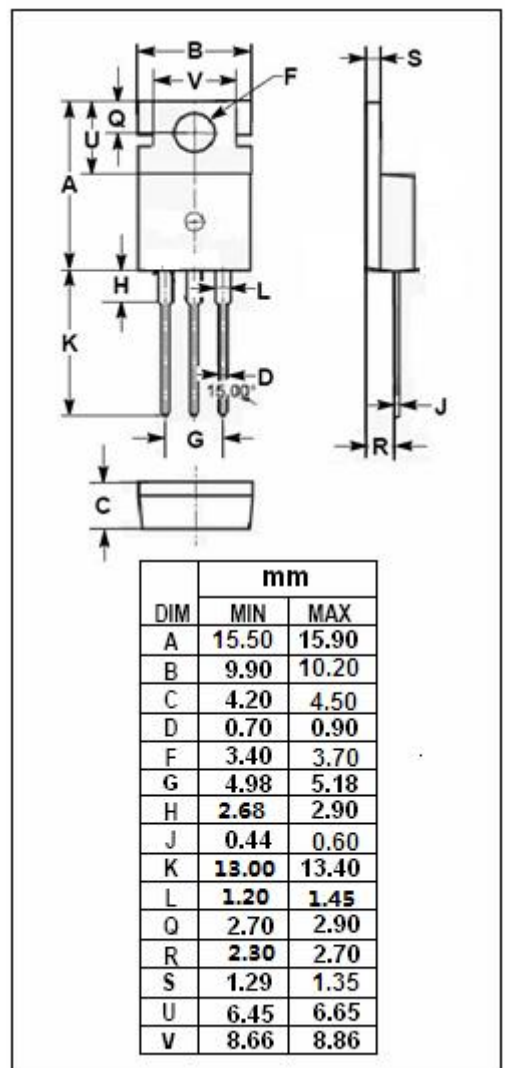
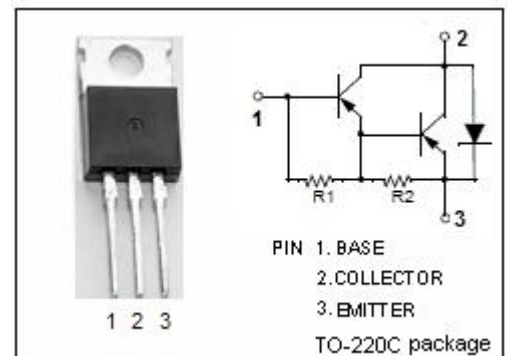
- Designed for general purpose amplifier and low speed switching applications.

ABSOLUTE MAXIMUM RATINGS($T_a = 25^\circ\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	-45	V
V_{CEO}	Collector-Emitter Voltage	-45	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current-Continuous	-10	A
I_{CM}	Collector Current-Peak	-15	A
I_B	Base Current-Continuous	-0.25	A
P_C	Collector Power Dissipation @ $T_C = 25^\circ\text{C}$	70	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	-65~150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th j-c}$	Thermal Resistance, Junction to Case	1.78	$^\circ\text{C/W}$



ELECTRICAL CHARACTERISTICS

 $T_C=25^{\circ}\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{CEO(SUS)}$	Collector-Emitter Sustaining Voltage	$I_C = -50\text{mA}; I_B = 0$	-45			V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = -4\text{A}; I_B = -8\text{mA}$			-2.5	V
$V_{BE(on)}$	Base-Emitter On Voltage	$I_C = -4\text{A}; V_{CE} = -3\text{V}$			-2.5	V
I_{CBO}	Collector Cutoff Current	$V_{CB} = -45\text{V}; I_E = 0$			-0.2	mA
I_{CEO}	Collector Cutoff Current	$V_{CE} = -22\text{V}; I_B = 0$			-0.5	mA
I_{EBO}	Emitter Cutoff Current	$V_{EB} = -5\text{V}; I_C = 0$			-10	mA
h_{FE}	DC Current Gain	$I_C = -4\text{A}; V_{CE} = -3\text{V}$	750			